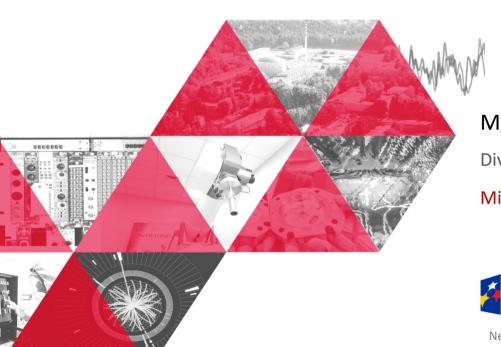
## Investigation of corrosion by means of adsorption energy analysis in DFT simulations





#### Michał Komorowicz

Division of Nuclear Energy and Environmental Studies

Michał.Komorowicz@ncbj.gov.pl









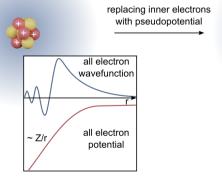
11.04.2023

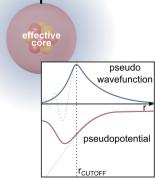
#### **Density Functional Theory**



- Method is based on the Hohenberg-Kohn Theorems
- Calculations are carried out using Kohn-Sham equations
- Electron structure is assessed by means of the potential acting on the electrons
- Potential depends solely on the type and arrangement of the atoms in the structure

- Projector-Augmented Wave (PAW) method based on Ultra-soft pseudo-potential
- Full all-electron wave functions and density
- Efficient and accurate





By Edvin Fako - Own work, CC BY-SA 4.0. https://commons.wikimedia.org/w/index.php?curid=98694995



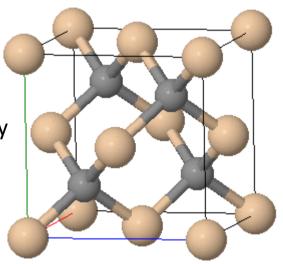
#### Studied cases



- 3C-SiC (β-SiC) highest electron mobility, saturation velocity and lowest Band gap (2.3eV) in all polytypes
- Zincblende structure FCC

#### Commonly occurring surfaces

- 100 Surface parallel to front surface, 4 fold symmetry
- 111 Surface plane intersecting x, y, z axes, 6 fold symmetry
- 110 Surface plane intersecting x, y axes, 2 fold symmetry

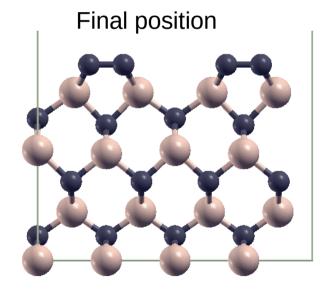


#### 100 Surface C- face



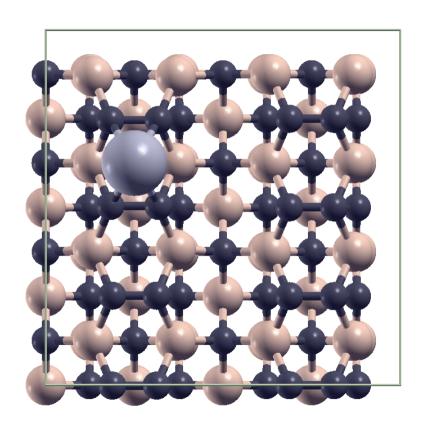
- C-C distance 1.36 Å
- Si-C 1.84 Å (1.66 in bulk crystal)
- Final energy = -4162.857 Ry

# Initial position









- Pb-C distance 2.48 Å
- Final energy = -5033.472 Ry

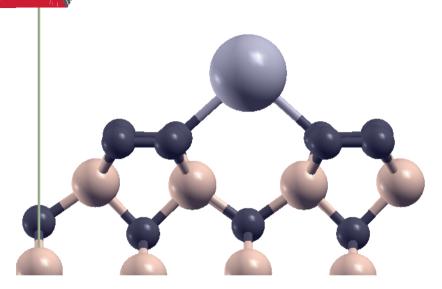
Adsorption energy calculation:

$$\mathbf{E}_{\text{adsorption}} = \left[ \mathbf{E}_{\text{system}} - \left( \mathbf{E}_{\text{adsorbent}} + \mathbf{E}_{\text{adsorbate}} \right) \right]$$

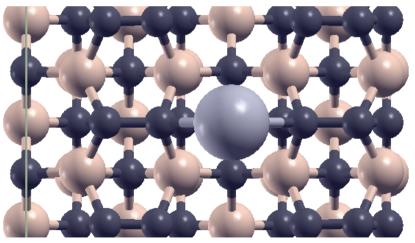
$$E_{adsorbate(Pb)} = -870.23 \text{ Ry}$$

• 
$$E_{adsorption} = -5.23 \text{ eV}$$



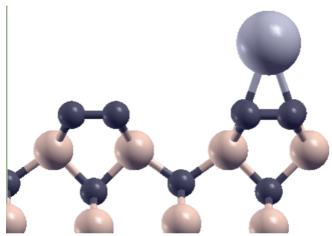


- Pb-C distance 2.52 Å
- Final energy = -5033.439 Ry
- $E_{adsorption} = -4.78 \text{ eV}$

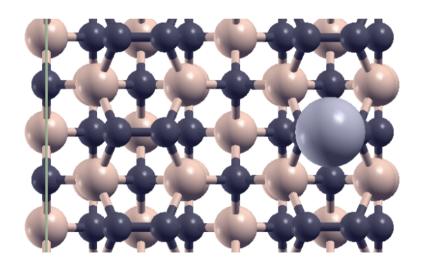






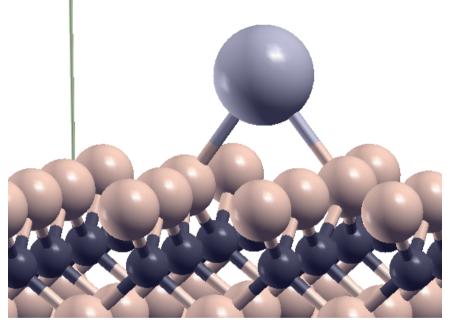


- Pb-C distance 2.30 Å
- Final energy = -5033.440 Ry
- $E_{adsorption} = -4.8 \text{ eV}$

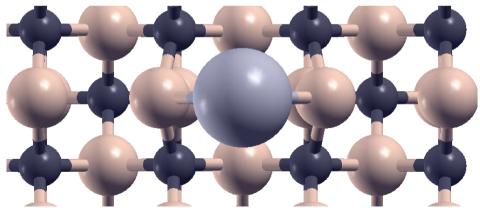


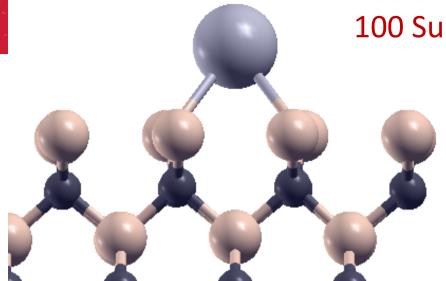
#### 100 Surface Si-face





- Final  $E_{adsorbent} = -4160.736$
- Pb-Si distance 2.77 Å
- Final energy = -5031.348 Ry
- $E_{adsorption} = -5.19 \text{ eV}$

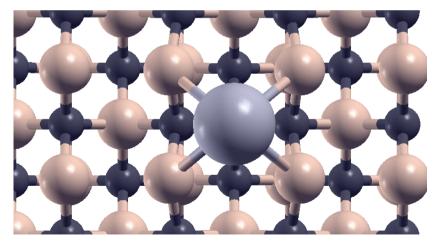






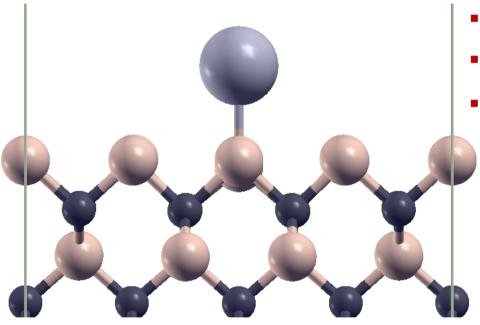


- Pb-Si distance 2.95 Å
- Final energy = -5031.378 Ry
- $E_{adsorption} = -5.6 \text{ eV}$







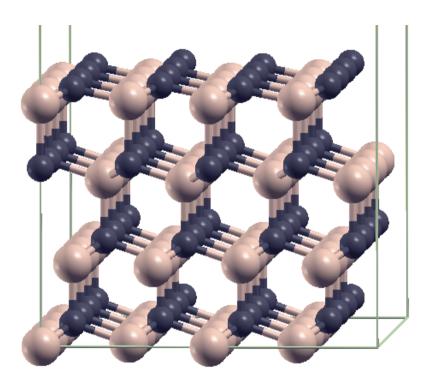


- Pb-Si distance 2.57 Å
- Final energy = -5031.272 Ry
- $E_{adsorption} = -4.16 \text{ Ry}$



#### 111 Surface C-face

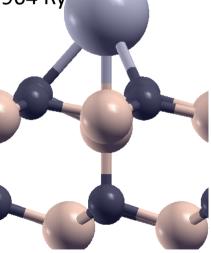




- Final  $E_{adsorbent} = -4168.232 \text{ Ry}$
- Pb-Si distance 2.67 Å
- Pb-C distance 2.55 Å

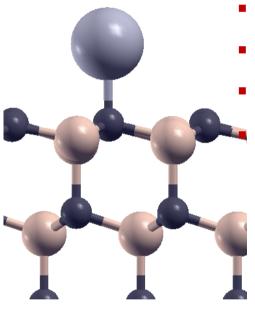
Final energy = -5038.964 Ry

•  $E_{adsorption} = -6.82 \text{ eV}$ 





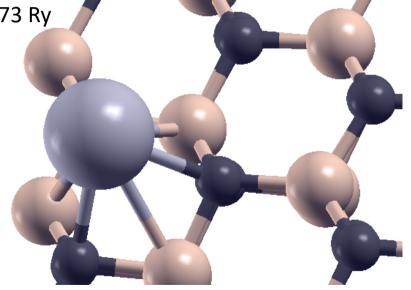




- Pb-Si distance 3.04 Å
- Pb-C distance 2.53 Å

Final energy = -5038.973 Ry

 $E_{adsorption}$  = -6.95 eV



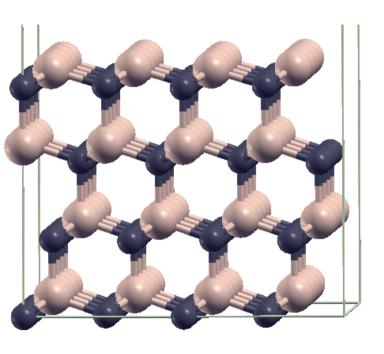
Initial position

Final position

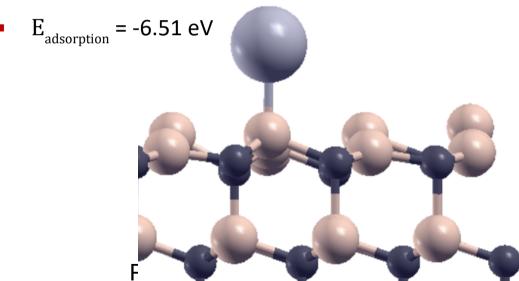


#### 111 Surface Si-face



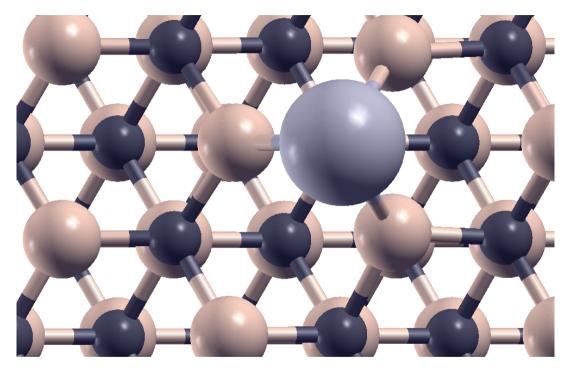


- Final  $E_{adsorbent} = -4167.902 \text{ Ry}$
- Pb-Si distance 2.64 Å
- Final energy = -5038.611 Ry





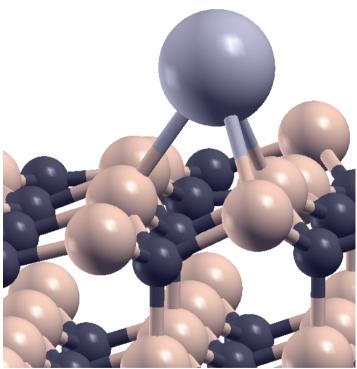




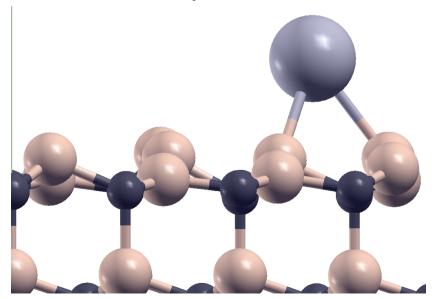
- Pb-Si distance 2.85, 2.87 Å
- Final energy = -5038.675 Ry
- $E_{adsorption} = -7.38 \text{ eV}$







- Pb-Si distance 2.85, 2.90 Å
- Final energy = -5038.667 Ry
- $E_{adsorption} = -7.27 \text{ eV}$





#### **Summary**



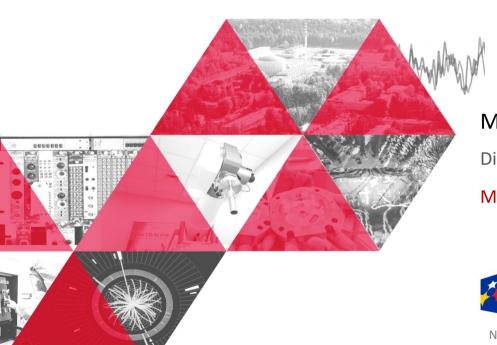
	100 Surface						111 Surface					
	C-face			Si-face			C-face			Si-face		
Position	gap	dimer	2 dimers	Si	2 Si	4 Si	Si	gap	gap	Si	gap	gap (C)
Energy [eV]	-4.78	-4.8	-5.23	-4.16	-5.19	-5.6	-6.82	-6.95	-6.95	-6.51	-7.27	-7.38

Lead ionization energy = 7.41 eV

- Shortest bond with lead is above C dimer on 100 surface 2.30 Å
   and longest in 111 C-face surface above interstitial site between Si 3.04 Å
- Currently 110 Surface is simulated
- All relaxed structures will be calculated using:
   Single-point (fixed-ion) SCF calculation with higher precision with other Pseudo-potentials

### Thank you for attention





#### Michał Komorowicz

Division of Nuclear Energy and Environmental Studies

Michał.Komorowicz@ncbj.gov.pl





